L Number	Hits	Search Text	DB	Time stamp
1	3295	parabolic adj mirror	USPAT;	2002/12/26 09:21
			US-PGPUB;	2002, 22, 20 03.21
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
2	9102	concave adj mirror	USPAT;	2002/12/26 08:50
		,	US-PGPUB;	2002/12/20 00:50
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
3	648	(oscillator or laser) same (parabolic adj	USPAT;	2002/12/26 08:54
		mirror)	US-PGPUB;	2002/12/20 00:54
		,	EPO; JPO;	
			DERWENT;	
			IBM TDB	
4	22	excimer and ((oscillator or laser) same	USPAT;	2002/12/26 08:54
		(parabolic adj mirror))	US-PGPUB;	2002/12/20 08:54
		(1	EPO; JPO;	
			DERWENT;	
			IBM TDB	
5	3162	convex adj mirror	USPAT;	2002/12/26 08:53
			US-PGPUB;	2002/12/20 00:55
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
6	604	(oscillator or laser) same (convex adj	USPAT;	2002/12/26 08:54
		mirror)	US-PGPUB;	2002/12/20 00:54
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
7	43	excimer and ((oscillator or laser) same	USPAT;	2002/12/26 08:54
		(convex adj mirror))	US-PGPUB;	2002/12/20 00:54
-		, , , , , , , , , , , , , , , , , , , ,	EPO; JPO;	
			DERWENT;	
			IBM TDB	
8	62	(excimer and ((oscillator or laser) same	USPAT;	2002/12/26 08:55
		(parabolic adj mirror))) (excimer and	US-PGPUB;	2002/12/20 00:00
		((oscillator or laser) same (convex adj	EPO; JPO;	
		mirror)))	DERWENT;	
	ľ		IBM TDB	
9	2	("5,995,265").PN.	USPAT;	2002/12/26 09:20
	~	· -,	US-PGPUB;	2002/12/20 03.20
			EPO; JPO;	
	ļ		DERWENT;	
			IBM TDB	
10	546	beam with homogenizer	USPAT;	2002/12/26 09:21
-			US-PGPUB;	2002/12/20 03:21
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
11	12	(parabolic adj mirror) and (beam with	USPAT;	2002/12/26 09:21
		homogenizer)	US-PGPUB;	
		•	EPO; JPO;	
			DERWENT;	
			IBM TDB	
			1 1 2 1 1 2 2	

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Author(s): Helen, Y.; Dassow, R.; Mourgues, K.; Bonnaud, O.;

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